74HC151-Q100; 74HCT151-Q100

8-input multiplexer Rev. 4 — 14 January 2021

Product data sheet

1. General description

The 74HC151-Q100; 74HCT151-Q100 are 8-bit multiplexer with eight binary inputs (I0 to I7), three select inputs (S0 to S2) and an enable input (\overline{E}). One of the eight binary inputs is selected by the select inputs and routed to the complementary outputs (Y and \overline{Y}). A HIGH on \overline{E} forces the output Y LOW and output \overline{Y} HIGH. Inputs also include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- · Specified in compliance with JEDEC standard no. 7A
- Input levels:
 - For 74HC151-Q100: CMOS level
 - For 74HCT151-Q100: TTL level
- Low-power dissipation
- · Non-inverting data path
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

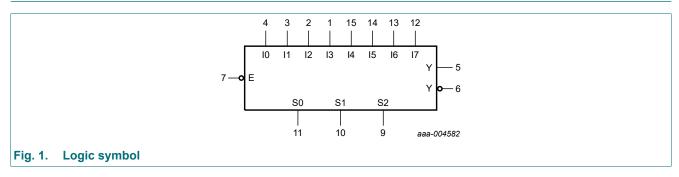
3. Ordering information

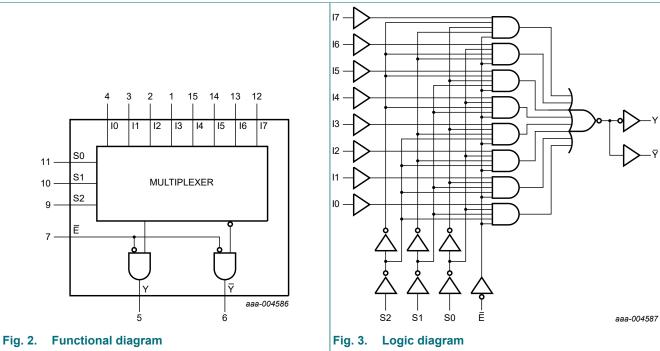
Table 1. Ordering information

Type number	Package	Package											
	Temperature range	Name	Description	Version									
74HC151D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1									
74HCT151D-Q100			body width 3.9 mm										
74HC151PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package;	SOT403-1									
74HCT151PW-Q100			16 leads; body width 4.4 mm										



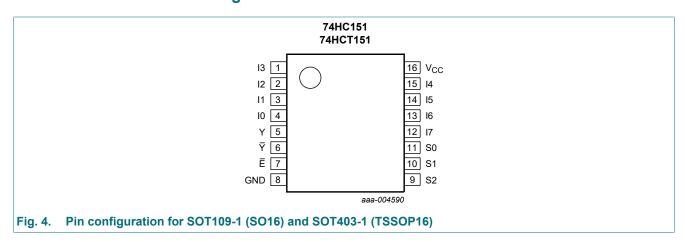
4. Functional diagram





5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
10 to 17	4, 3, 2, 1, 15, 14, 13, 12	data inputs
Υ	5	multiplexer output
Y	6	complementary multiplexer output
E	7	enable input (active LOW)
GND	8	ground (0 V)
S0, S1, S2	11, 10, 9	common data select inputs
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$

Input												Outp	Output		
Ē	S2	S1	S0	10	I1	12	13	14	15	16	17	Y	Υ		
Н	Х	X	X	Х	Х	Х	Х	Х	Х	Х	Х	Н	L		
L	L	L	L	L	Х	Х	Х	Х	Х	Х	Х	Н	L		
L	L	L	L	Н	Х	Х	Х	Х	Х	Х	Х	L	Н		
L	L	L	Н	Х	L	Х	X	Х	Х	Х	Х	Н	L		
L	L	L	Н	Х	Н	Х	Х	Х	Х	Х	Х	L	Н		
L	L	Н	L	Х	Х	L	X	Х	Х	Х	Х	Н	L		
L	L	Н	L	Х	Х	Н	Х	Х	Х	Х	Х	L	Н		
L	L	Н	Н	Х	Х	Х	L	Х	Х	Х	Х	Н	L		
L	L	Н	Н	Х	Х	Х	Н	Х	Х	Х	Х	L	Н		
L	Н	L	L	Х	Х	Х	X	L	Х	Х	Х	Н	L		
L	Н	L	L	Х	Х	Х	X	Н	Х	Х	Х	L	Н		
L	Н	L	Н	Х	X	X	X	Х	L	X	X	Н	L		
L	Н	L	Н	Х	Х	Х	Х	Х	Н	Х	Х	L	Н		
L	Н	Н	L	Х	Х	Х	X	Х	Х	L	Х	Н	L		
L	Н	Н	L	Х	Х	X	Х	Х	Х	Н	Х	L	Н		
L	Н	Н	Н	Х	Х	Х	Х	Х	Х	Х	L	Н	L		
L	Н	Н	Н	Х	X	X	Х	Х	Х	Х	Н	L	Н		

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _O	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$		-	±25	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[1]	-	500	mW

^[1] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	741	1C151-Q	100	74H	Unit		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C -			-40 °C to	+85 °C	-40 °C to	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
74HC15	1-Q100									
V_{IH}	V _{IH} HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
inp		V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	1
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level $V_I = V_{IH}$ or V_{IL}									
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
	$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$		-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	51-Q100						'		'	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; I_O = 0 A								
		per input pin; In inputs	-	45	162	-	203	-	221	μΑ
		per input pin; E input	-	30	108	-	135	-	147	μΑ
		per input pin; Sn input	-	150	540	-	675	-	735	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit see Fig. 7.

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to	Unit	
				Min	Тур	Max	Min	Max	Min	Max	1
74HC15	1-Q100				'				<u>'</u>	-	
t _{pd}	propagation	In to Y; see Fig. 5	[1]								
	delay	V _{CC} = 2.0 V		-	52	170	-	215	-	255	ns
		V _{CC} = 4.5 V		-	19	34	-	43	-	51	ns
		V _{CC} = 5 V; C _L = 15 pF		-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V		-	15	29	-	37	-	43	ns
		In to ₹; see Fig. 5	[1]								
		V _{CC} = 2.0 V		-	58	185	-	230	-	280	ns
		V _{CC} = 4.5 V		-	21	37	-	46	-	56	ns
		V _{CC} = 5 V; C _L = 15 pF		-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V		-	17	31	-	39	-	48	ns
		Sn to Y; see Fig. 6	[1]								
		V _{CC} = 2.0 V		-	61	185	-	230	-	280	ns
		V _{CC} = 4.5 V		-	22	37	-	46	-	56	ns
		V _{CC} = 5 V; C _L = 15 pF		-	19	-	-	-	-	-	ns
		V _{CC} = 6.0 V		-	18	31	-	39	-	48	ns
		Sn to Y ; see <u>Fig. 6</u>	[1]								
		V _{CC} = 2.0 V		-	61	205	-	255	-	310	ns
		V _{CC} = 4.5 V		-	22	41	-	51	-	62	ns
		V _{CC} = 5 V; C _L = 15 pF		-	19	-	-	-	-	-	ns
		V _{CC} = 6.0 V		-	18	35	-	43	-	53	ns
		Ē to Y; see <u>Fig. 6</u>									
		V _{CC} = 2.0 V		-	41	125	-	155	-	190	ns
		V _{CC} = 4.5 V		-	15	25	-	31	-	38	ns
		V _{CC} = 5 V; C _L = 15 pF		-	12	-	-	-	-	-	ns
		V _{CC} = 6.0 V		-	12	21	-	26	-	32	ns
		Ē to ₹; see Fig. 6									
		V _{CC} = 2.0 V		-	47	145	-	180	-	220	ns
		V _{CC} = 4.5 V		-	17	29	-	36	-	44	ns
		V _{CC} = 5 V; C _L = 15 pF		-	14	-	-	-	-	-	ns
		V _{CC} = 6.0 V		-	14	25	-	31	-	38	ns
t _t	transition	Y, \overline{Y} ; see Fig. 5	[2]								
	time	V _{CC} = 2.0 V		-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V		-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V		-	6	13	-	16	-	19	ns
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V_I = GND to V_{CC}	[3]	-	40	-	-	-	-	-	pF

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
74HCT1	51-Q100								<u>'</u>	-	
t _{pd}	propagation	In to Y; see Fig. 5	[1]								
	delay	V _{CC} = 4.5 V		-	22	38	-	48	-	57	ns
		V _{CC} = 5 V; C _L = 15 pF		-	19	-	-	-	-	-	ns
		In to ₹; see Fig. 5	[1]								
		V _{CC} = 4.5 V		-	22	38	-	48	-	57	ns
		V _{CC} = 5 V; C _L = 15 pF		-	19	-	-	-	-	-	ns
		Sn to Y; see Fig. 6	[1]								
		V _{CC} = 4.5 V		-	23	41	-	51	-	62	ns
		V _{CC} = 5 V; C _L = 15 pF		-	20	-	-	-	-	-	ns
		Sn to ₹; see Fig. 6	[1]								
		V _{CC} = 4.5 V		-	25	43	-	54	-	65	ns
		V _{CC} = 5 V; C _L = 15 pF		-	20	-	-	-	-	-	ns
		E to Y; see Fig. 6	[1]								
		V _{CC} = 4.5 V		-	16	29	-	36	-	44	ns
		V _{CC} = 5 V; C _L = 15 pF		-	13	-	-	-	-	-	ns
		E to ∀; see Fig. 6	[1]								
		V _{CC} = 4.5 V		-	21	36	-	45	-	54	ns
		V _{CC} = 5 V; C _L = 15 pF		-	18	-	-	-	-	-	ns
t _t	transition	Y, ₹; see <u>Fig. 5</u>	[2]								
	time	V _{CC} = 4.5 V		-	7	15	-	19	-	22	ns
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V_I = GND to V_{CC} - 1.5 V	[3]	-	40	-	-	-	-	-	pF

- $\begin{array}{ll} [1] & t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}. \\ [2] & t_t \text{ is the same as } t_{THL} \text{ and } t_{TLH}. \\ [3] & C_{PD} \text{ is used to determine the dynamic power dissipation } (P_D \text{ in } \mu\text{W}). \\ & P_D = C_{PD} \times V_{CC}^{\ \ 2} \times f_i \times N + \Sigma (C_L \times V_{CC}^{\ \ 2} \times f_o) \text{ where:} \end{array}$

 f_i = input frequency in MHz;

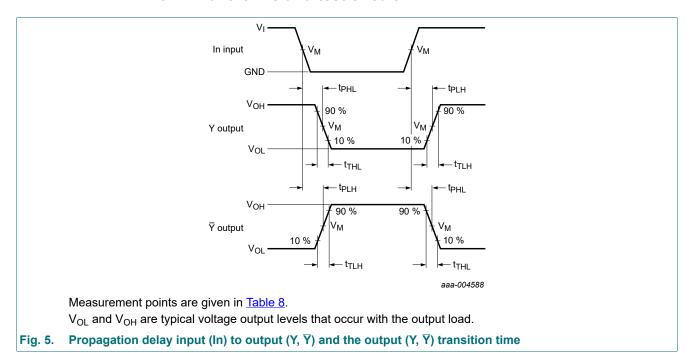
f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

10.1. Waveforms and test circuit



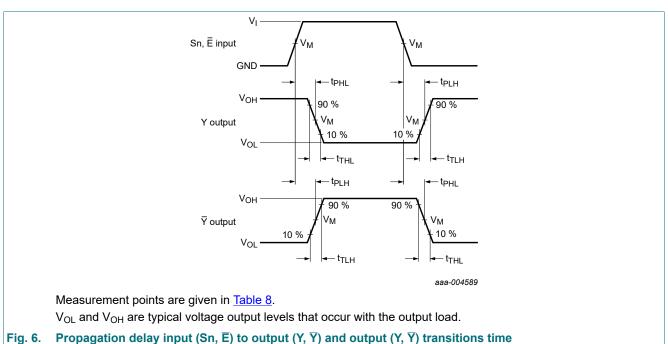
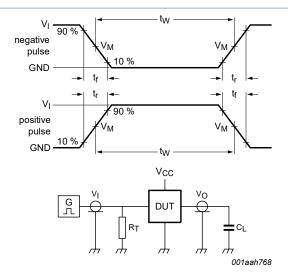


Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74HC151-Q100	0.5V _{CC}	0.5V _{CC}
74HCT151-Q100	1.3 V	1.3 V



Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig. 7. Test circuit for measuring switching times

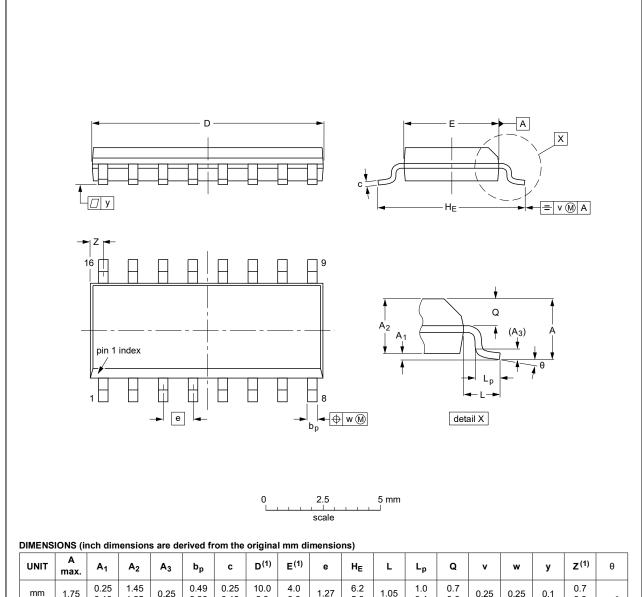
Table 9. Test data

Туре	Input		Load	Test
	V _I	t _r , t _f	C _L	
74HC151-Q100	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74HCT151-Q100	3.0 V	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

11. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UN	IT ma		A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mr	n 1.1	75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inch	es 0.0	069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

Note

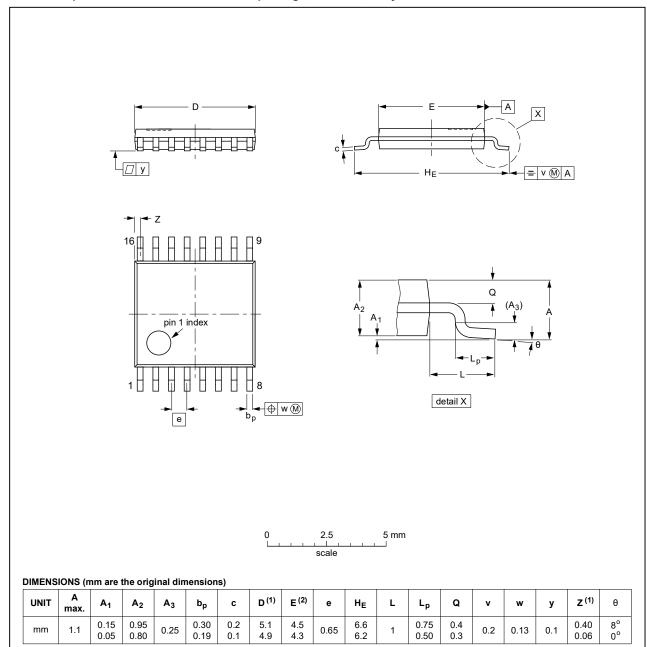
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				99-12-27 03-02-19

Fig. 8. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				99-12-27 03-02-18

Fig. 9. Package outline SOT403-1 (TSSOP16)

12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Table 11. Nevision mistory						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT151_Q100 v.4	20210114	Product data sheet	-	74HC_HCT151_Q100 v.3		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Section 7: Derating values for P_{tot} total power dissipation have been updated. 					
74HC_HCT151_Q100 v.3	20150126	Product data sheet	-	74HC_HCT151_Q100 v.2		
Modifications:	<u>Table 7</u> : Power dissipation capacitance condition for 74HCT151-Q100 is corrected.					
74HC_HCT151_Q100 v.2	20130211	Product data sheet	-	74HC_HCT151_Q100 v.1		
Modifications:	New descriptive title (errata).					
74HC_HCT151_Q100 v.1	20120807	Product data sheet	-	-		

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

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